

μPD5902T7K

R09DS0046EJ0200

Rev.2.00

Nov 19, 2012

CMOS Integrated Circuits High Power SPDT Switch

DESCRIPTION

The μPD5902T7K is a CMOS MMIC SPDT (Single Pole Double Throw) switch for GSM and UMTS/LTE main Antenna switching and other High Power RF switching applications up to +35 dBm.

This device can operate frequency from 0.05 to 6.0 GHz, having low insertion loss and high isolation.

This device is housed in a 12-pin plastic QFN (Quad Flat Non-Leaded) (T7K) package.

FEATURES

- Low control voltage : $V_{cont} = 1.3 \text{ V MIN.}$, $V_{DD} = 2.3 \text{ V MIN.}$
- Low insertion loss : $L_{ins} = 0.35/0.40 \text{ dB TYP. @ } f = 1.0/2.0 \text{ GHz}$
- High isolation : $ISL = 45/37 \text{ dB TYP. @ } f = 1.0/2.0 \text{ GHz}$
- High Handling power : $P_{in(0.1dB)} = +38 \text{ dBm TYP. @ } f = 0.9/2.0 \text{ GHz}$
- High-density surface mounting : 12-pin plastic QFN (T7K) package (2.0 × 2.0 × 0.6 mm)
- No DC blocking capacitors required.

APPLICATIONS

- GSM and UMTS/LTE main Antenna switching etc.
- Other RF switching Applications.
- Antenna tuning Applications.

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μPD5902T7K-E2	μPD5902T7K-E2-A	12-pin plastic QFN (T7K) (Pb-Free)	5902	<ul style="list-style-type: none"> • Embossed tape 8 mm wide • Pin 10, 11 and 12 face the perforation side of the tape • Qty 3 kpcs/reel

Remark To order evaluation samples, please contact your nearby sales office.

Part number for sample order: μPD5902T7K-A

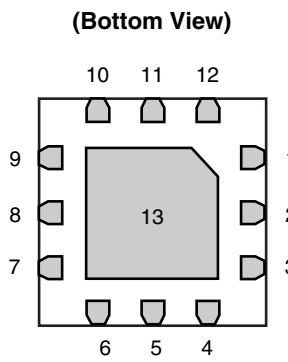
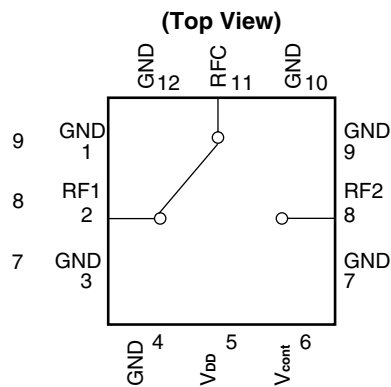
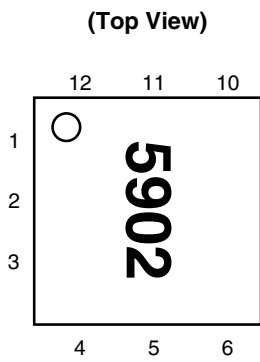
CAUTION

Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions must be employed at all times.

The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

<R> PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	GND
2	RF1
3	GND
4	GND
5	V _{DD}
6	V _{cont}
7	GND
8	RF2
9	GND
10	GND
11	RFC
12	GND
13	GND

SW TRUTH TABLE

V _{cont}	RFC–RF1	RFC–RF2
High	ON	OFF
Low	OFF	ON

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Supply Voltage	V _{DD}	3.6	V
Control Voltage	V _{cont}	3.6	V
Input Power	P _{in}	+38	dBm
Operating Ambient Temperature	T _A	–40 to +85	°C
Storage Temperature	T _{stg}	–55 to +125	°C

RECOMMENDED OPERATING RANGE (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Operating Frequency	f	0.05	–	6.0	GHz
Supply Voltage	V _{DD}	2.3	–	3.3	V
Control Voltage (High)	V _{cont (H)} ^{Note}	1.3	–	V _{DD}	V
Control Voltage (Low)	V _{cont (L)}	0	–	0.4	V

Note: V_{cont} ≤ V_{DD}

ELECTRICAL CHARACTERISTICS

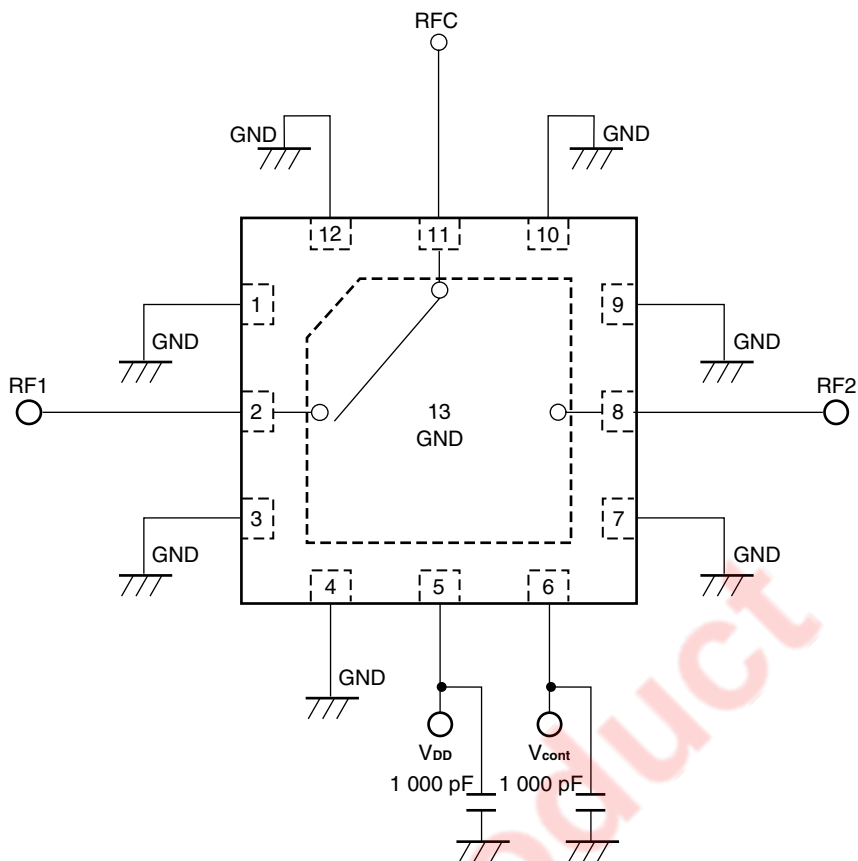
(T_A = +25°C, V_{DD} = 2.5 V, V_{cont} (H) = 1.8 V, V_{cont} (L) = 0 V, Z₀ = 50 Ω, unless otherwise specified)

<R>

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss	L _{ins1}	f = 0.05 to 0.5 GHz, P _{in} = 0 dBm	-	0.30	0.45	dB
	L _{ins2}	f = 0.5 to 1.0 GHz	-	0.35	0.50	
	L _{ins3}	f = 1.0 to 2.0 GHz	-	0.40	0.55	
	L _{ins4}	f = 2.0 to 2.7 GHz	-	0.45	0.75	
	L _{ins5}	f = 2.7 to 3.8 GHz	-	0.50	0.80	
	L _{ins6}	f = 3.8 to 6.0 GHz	-	0.60	0.95	
Isolation (RFC – RF1,2)	ISL1	f = 0.05 to 0.5 GHz, P _{in} = 0 dBm	45	50	-	
	ISL2	f = 0.5 to 1.0 GHz	40	45	-	
	ISL3	f = 1.0 to 2.0 GHz	32	37	-	
	ISL4	f = 2.0 to 2.7 GHz	30	35	-	
	ISL5	f = 2.7 to 3.8 GHz	25	30	-	
	ISL6	f = 3.8 to 6.0 GHz	-	23	-	
Return Loss (RFC)	RL1	f = 0.05 to 3.8 GHz	15	18	-	
	RL2	f = 3.8 to 6.0 GHz	-	15	-	
Return Loss (RF1,2)	RL1	f = 0.05 to 3.8 GHz	15	18	-	
	RL2	f = 3.8 to 6.0 GHz	-	15	-	
0.1 dB Loss Compression Input Power	P _{in(0.1dB)1}	f = 0.9 GHz	+36.0	+38.0 Note	-	dBm
	P _{in(0.1dB)2}	f = 2.0 GHz	+36.0	+38.0 Note	-	
Harmonics	2f ₀	f = 0.9 GHz, P _{in} = +35 dBm	75	80	-	dBc
	3f ₀		70	75	-	
	2f ₀	f = 2.0 GHz, P _{in} = +33 dBm	75	85	-	
	3f ₀		70	80	-	
2nd Order Inter Modulation Distortion	IMD2	f = 835 MHz, P _{in} = +20 dBm f = 45 MHz, P _{in} = -15 dBm	-	-98	-93	dBm
		f = 1 950 MHz, P _{in} = +20 dBm f = 190MHz, P _{in} = -15 dBm	-	-105	-100	
3rd Order Inter Modulation Distortion	IMD3	f = 835 MHz, P _{in} = +20 dBm f = 790 MHz, P _{in} = -15 dBm	-	-110	-105	
		f = 1 950 MHz, P _{in} = +20 dBm f = 1 760 MHz, P _{in} = -15 dBm	-	-110	-105	
Input 3rd order Intercept Point	IIP ₃	f = 2 500 MHz, P _{in} = +20 dBm f = 2 501 MHz, P _{in} = +20 dBm	65	70	-	dBm
Switch Control Speed	T _{sw}	50% CTL to 90/10%	-	2.0	5.0	μsec
Supply Current	I _{DD}	Active Mode No RF	-	130	250	μA
Control Current	I _{cont} (H)	V _{cont} : High No RF	-	-	1	
	I _{cont} (L)	V _{cont} : Low No RF	-	-	1	

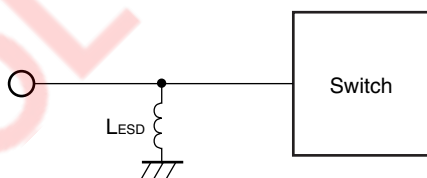
Note: Absolute Maximum Ratings

<R> EVALUATION CIRCUIT



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

APPLICATION INFORMATION

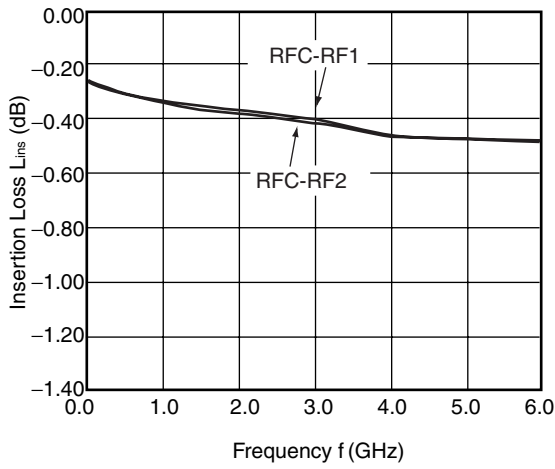


- L_{ESD} provides a means to increase the ESD protection on a specific RF port, typically the port attached to the antenna.

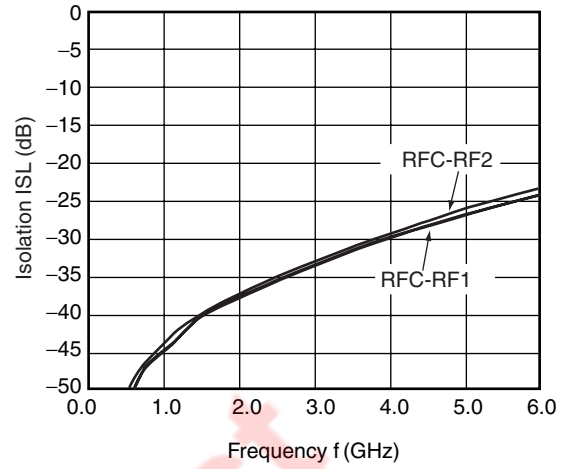
TYPICAL CHARACTERISTICS

($T_A = +25^{\circ}\text{C}$, $V_{DD} = 2.5\text{ V}$, $V_{\text{cont (H)}} = 1.8\text{ V}$, $V_{\text{cont (L)}} = 0\text{ V}$, $Z_0 = 50\ \Omega$, unless otherwise specified)

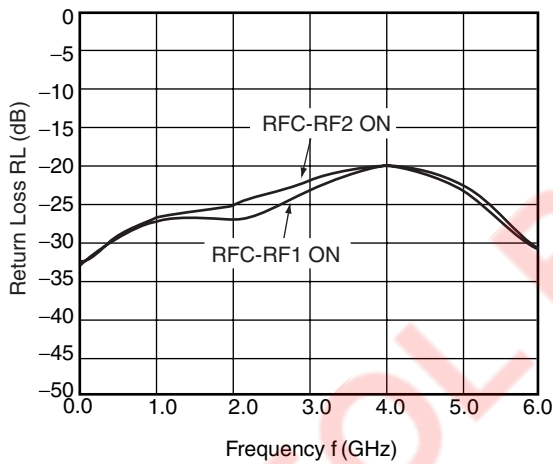
RFC-RF1/RF2
INSERTION LOSS vs. FREQUENCY



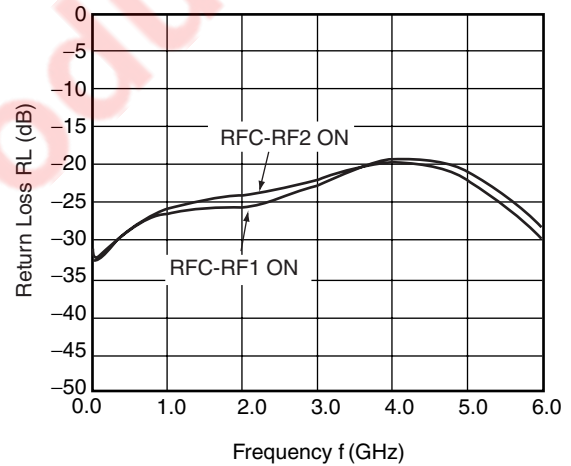
RFC-RF1/RF2
ISOLATION vs. FREQUENCY



RFC
RETURN LOSS vs. FREQUENCY

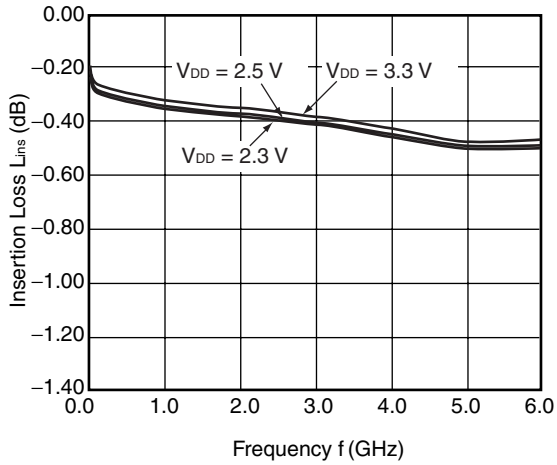


RF1/RF2
RETURN LOSS vs. FREQUENCY

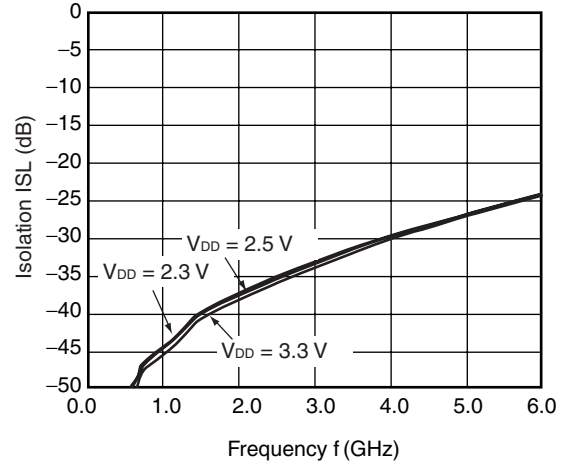


Remark The graphs indicate nominal characteristics.

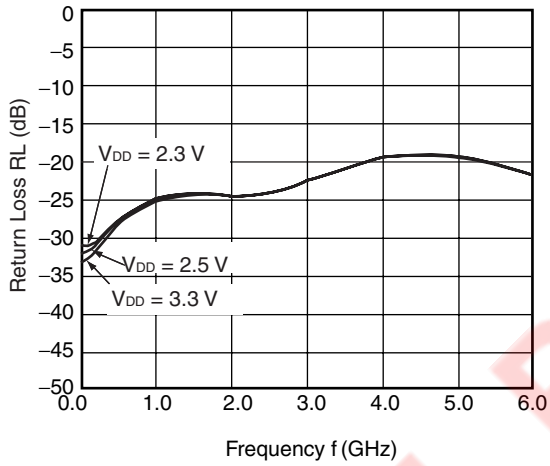
RFC-RF1/RF2
INSERTION LOSS vs. FREQUENCY



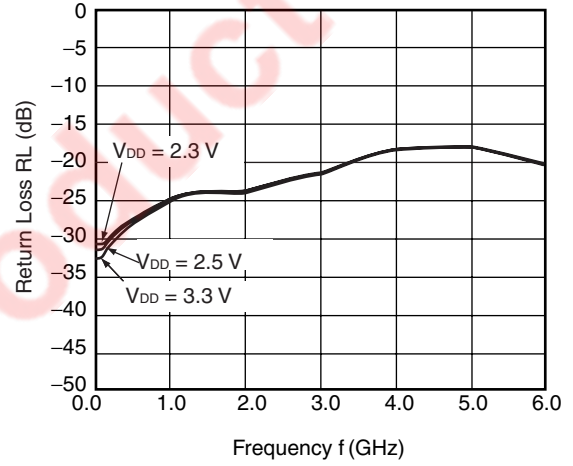
RFC-RF1/RF2
ISOLATION vs. FREQUENCY



RFC
RETURN LOSS vs. FREQUENCY

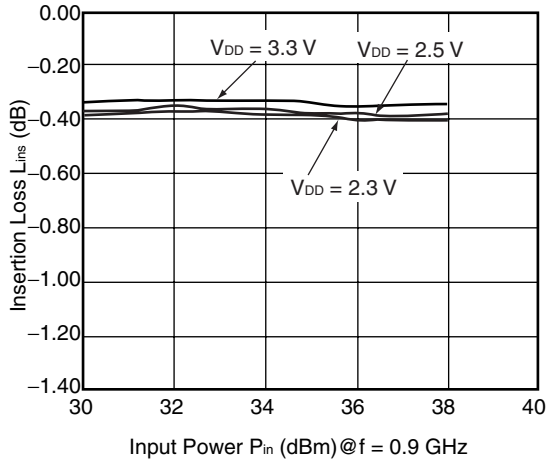


RF1/RF2
RETURN LOSS vs. FREQUENCY

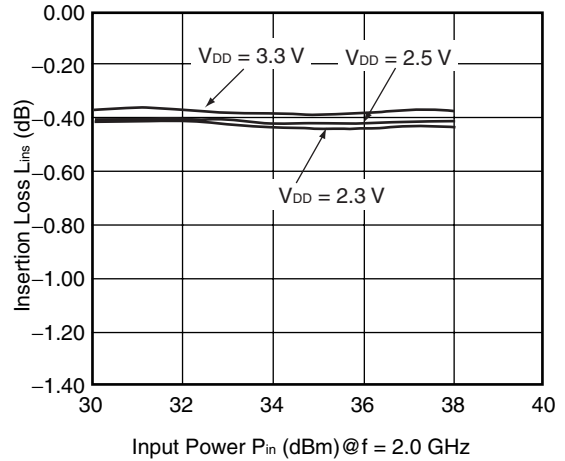


Remark The graphs indicate nominal characteristics.

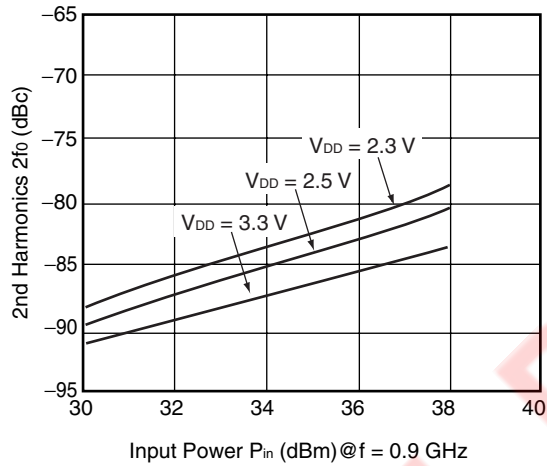
RFC-RF1/RF2
INSERTION LOSS vs. INPUT POWER



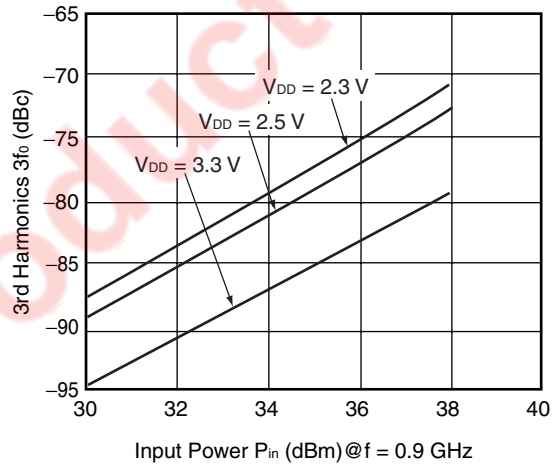
RFC-RF1/RF2
INSERTION LOSS vs. INPUT POWER



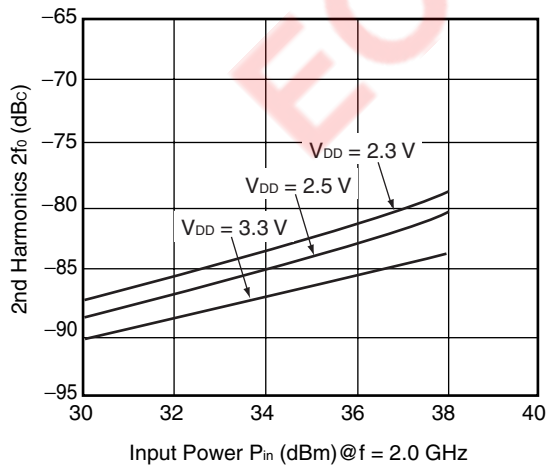
RFC-RF1/RF2
2nd HARMONICS vs. INPUT POWER



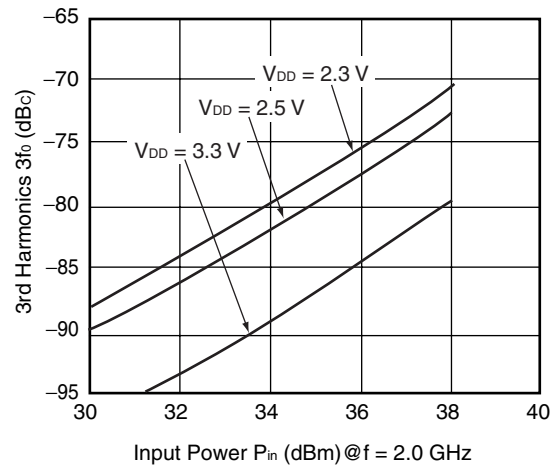
RFC-RF1/RF2
3rd HARMONICS vs. INPUT POWER



RFC-RF1/RF2
2nd HARMONICS vs. INPUT POWER

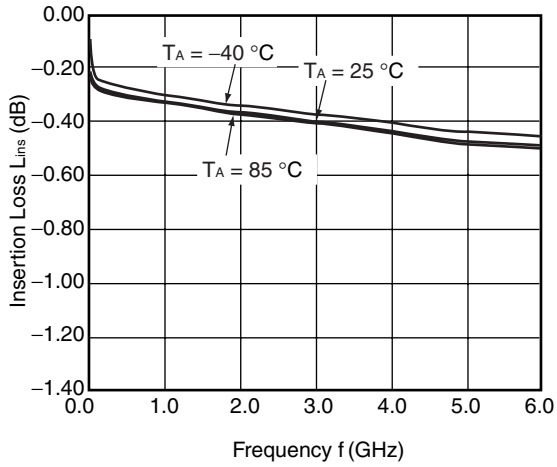


RFC-RF1/RF2
3rd HARMONICS vs. INPUT POWER

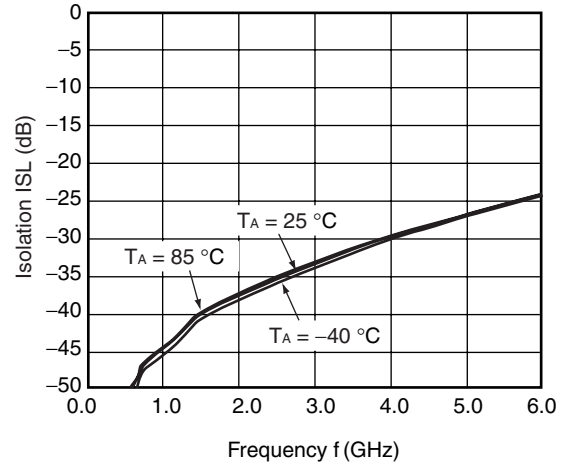


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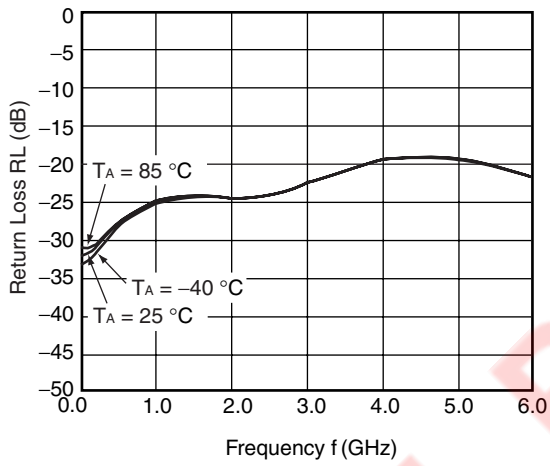
RFC-RF1/RF2
INSERTION LOSS vs. FREQUENCY



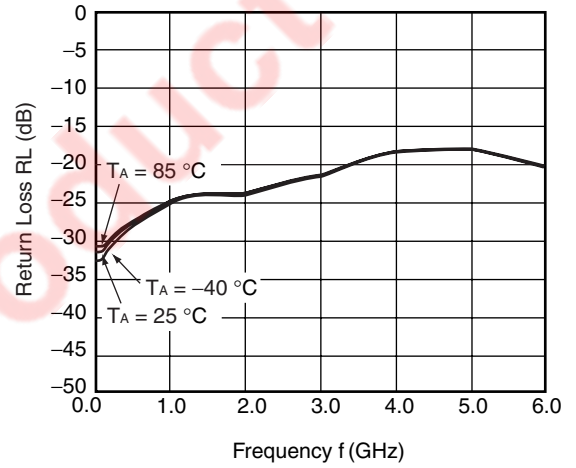
RFC-RF1/RF2
ISOLATION vs. FREQUENCY



RFC
RETURN LOSS vs. FREQUENCY

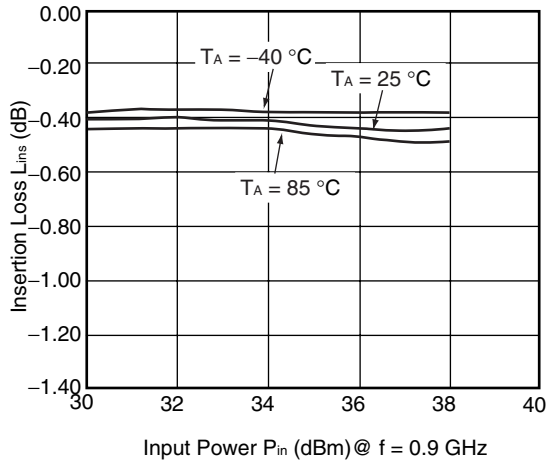


RF1/RF2
RETURN LOSS vs. FREQUENCY

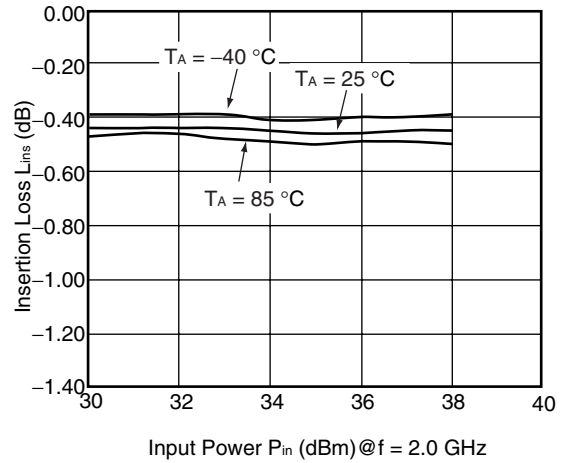


Remark The graphs indicate nominal characteristics.

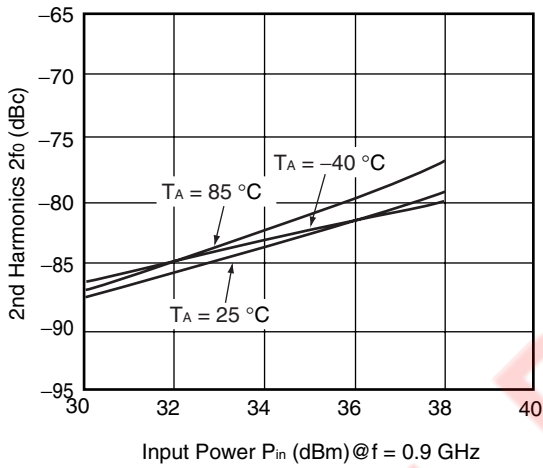
RFC-RF1/RF2
INSERTION LOSS vs. INPUT POWER



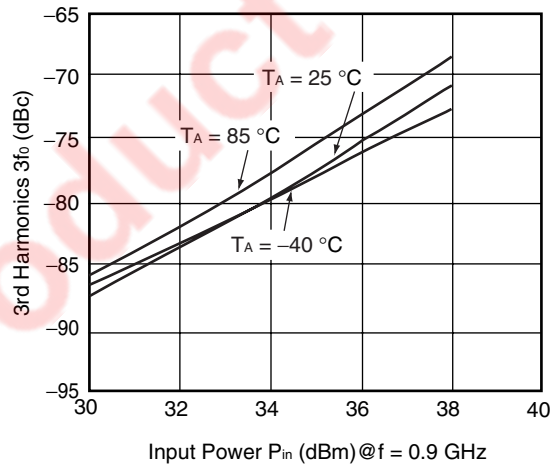
RFC-RF1/RF2
INSERTION LOSS vs. INPUT POWER



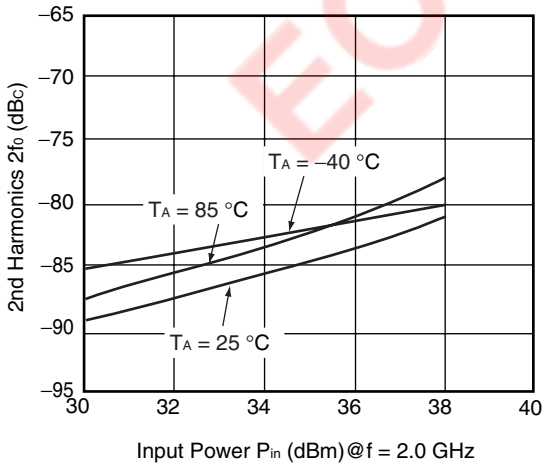
RFC-RF1/RF2
2nd HARMONICS vs. INPUT POWER



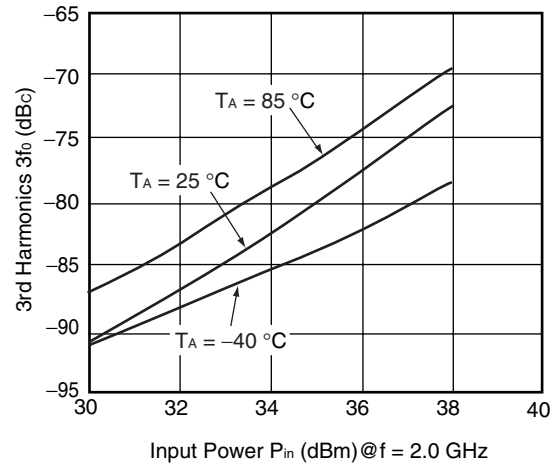
RFC-RF1/RF2
3rd HARMONICS vs. INPUT POWER



RFC-RF1/RF2
2nd HARMONICS vs. INPUT POWER



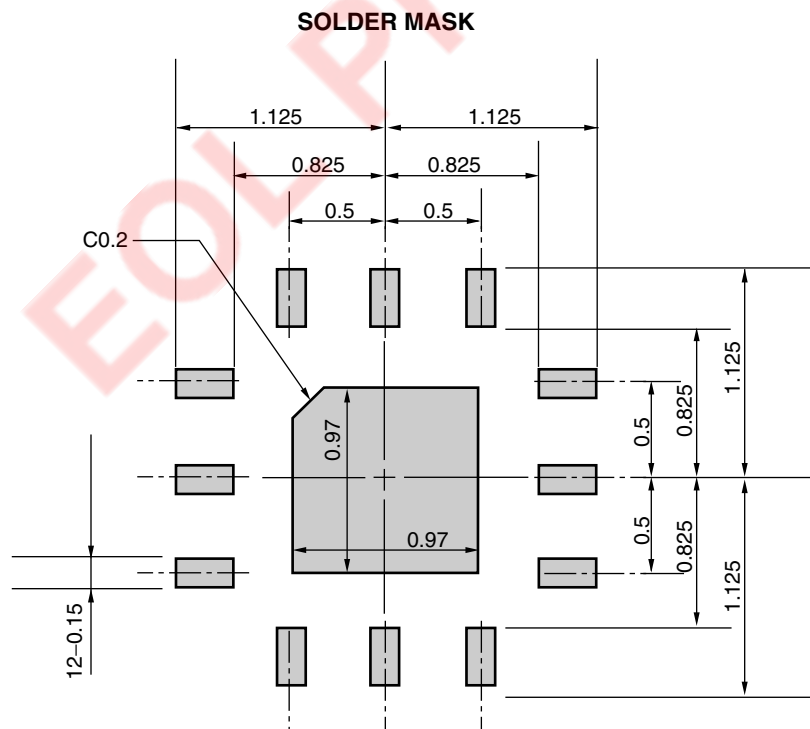
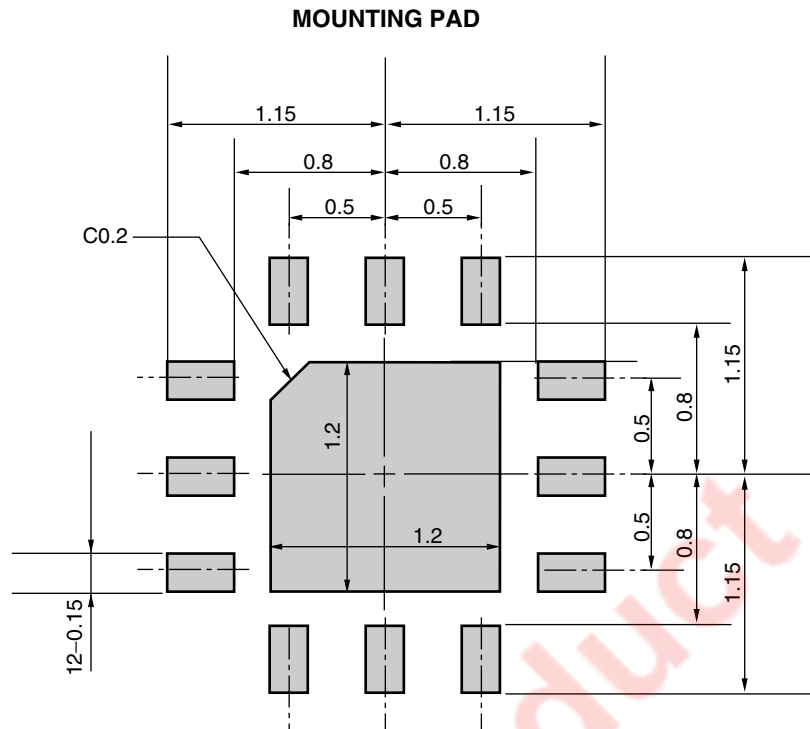
RFC-RF1/RF2 3rd HARMONICS vs.
INPUT POWER



Remark The graphs indicate nominal characteristics.

MOUNTING PAD LAYOUT DIMENSIONS

12-PIN PLASTIC QFN (T7K) (UNIT: mm)



Solder thickness : 0.1 mm

Remark The mounting pad layout in this document is for reference only.
When designing PCB, please consider workability of mounting, solder joint reliability, prevention of solder bridge and so on, in order to optimize the design.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2% (Wt.) or below	IR260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2% (Wt.) or below	HS350

CAUTION

Do not use different soldering methods together (except for partial heating).

EOL Product

Revision History	μPD5902T7K Data Sheet
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Rev.	Date	Description	
		Page	Summary
1.00	Sep 10, 2012	–	First edition issued
2.00	Nov 19, 2012	p.2	The block diagram is changed.
		p.3	The symbol indicating the range between terminals is changed from “to” to “-”.
		p.4	The evaluation circuit is changed.

EOL Product

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California Eastern Laboratories, Inc.
4590 Patrick Henry Drive, Santa Clara, California 95054, U.S.A.
Tel: +1-408-919-2500, Fax: +1-408-988-0279

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

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Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd.
11F., Samik Lavied' or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141